TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOS VII)

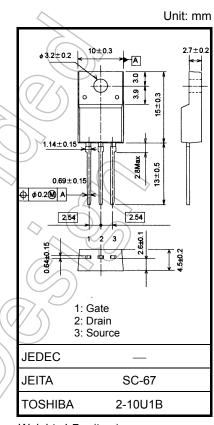
TK11A60D

Switching Regulator Applications

- Low drain-source ON resistance: $RDS(ON) = 0.54 \Omega$ (typ.)
- High forward transfer admittance: $|Y_{fs}| = 6.0 \text{ S}$ (typ.)
- Low leakage current: $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 600 \ V)$
- Enhancement-mode: $V_{th} = 2.0$ to 4.0 V ($V_{DS} = 10$ V, $I_D = 1$ mA)

| | • | • | • | 21 |
|---|----------------|---------------------|---------------------------------------|---------------------------------------|
| Characteristics | | Symbol | Rating | Unit |
| Drain-source voltage | | V _{DSS} | 600 | $(\underline{\forall}\underline{v}))$ |
| Gate-source voltage | | V _{GSS} | ±30 | V |
| Drain current | DC (Note 1) | Ι _D | 11 | |
| | Pulse (Note 1) | I _{DP} | 44 | > A |
| Drain power dissipation (Tc = 25°C) | | PD | 45 | W |
| Single pulse avalanche energy (Note 2) | | Eas | 396 | mJ |
| Avalanche current | | IAR | 11 | A |
| Repetitive avalanche energy (Note 3) | | EAR | 4.5 | mJ |
| Channel temperature | | Тсп | 150 | °C |
| Storage temperature range | | (T _{stg}) | -55 to 150 | °C |
| | | | · · · · · · · · · · · · · · · · · · · | 10 |





Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|--|------------------------|------|------|
| Thermal resistance, channel to case | Rth (ch-c) | 2.78 | °C/W |
| Thermal resistance, channel to ambient | R _{th (ch-a)} | 62.5 | °C/W |

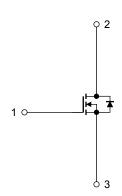
Note 1: Please use devices on conditions that the channel temperature is below 150°C.

Note 2:
$$V_{DD}$$
 = 90 V, T_{ch} = 25°C (initial), L = 5.73 mH, R_G = 25 Ω , I_{AR} = 11 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic sensitive device. Please handle with caution.

Internal Connection



Start of commercial production 2008-09

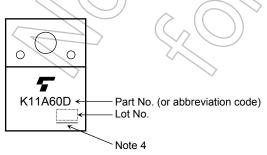
Electrical Characteristics (Ta = 25°C)

| Char | acteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|------------------------------|----------------|----------------------|---|---------------|------|------------|------|
| Gate leakage cu | rrent | I _{GSS} | $V_{GS}=\pm 30~V,~V_{DS}=0~V$ | — | | ±1 | μA |
| Drain cut-off curr | rent | IDSS | $V_{DS} = 600 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$ | | | 10 | μA |
| Drain-source bre | akdown voltage | V (BR) DSS | $I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$ | 600 | | | V |
| Gate threshold v | oltage | V _{th} | $V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$ | 2.0 | | 4.0 | V |
| Drain-source ON | resistance | R _{DS (ON)} | $V_{GS} = 10 \text{ V}, \text{ I}_{D} = 5.5 \text{ A}$ | F | 0.54 | 0.65 | Ω |
| Forward transfer | admittance | Y _{fs} | $V_{DS} = 10 \text{ V}, \text{ I}_{D} = 5.5 \text{ A}$ | 1.5 | 6.0 | | S |
| Input capacitance | | C _{iss} | | Θ | 1550 | | |
| Reverse transfer capacitance | | C _{rss} | $V_{DS} = 25 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ f} = 1 \text{ MHz}$ | _ | 7 | | pF |
| Output capacitance | | C _{oss} | | 7 — | 165 | | |
| Switching time | Rise time | tr | $\begin{array}{c} 10 \text{ V} \\ \text{V}_{\text{GS}} \\ 0 \text{ V} \\ 50 \Omega \end{array} \begin{array}{c} \text{I}_{\text{D}} = 5.5 \text{ A} \\ \text{V}_{\text{OUT}} \\ \text{O} \\ \text{V}_{\text{OUT}} \\ \text{O} \\ \text{O} \\ \text{O} \\ \text{S} \\ \text{R}_{\text{L}} = 36 \Omega \end{array}$ | — | 25 | \swarrow | . ns |
| | Turn-on time | t _{on} | | | 60 | | |
| | Fall time | t _f | /// V _{DD} ≈ 200 V | | 15 | / | |
| | Turn-off time | t _{off} | Duty \leq 1%, t _W = 10 μ s | \mathcal{T} | 110 | — | |
| Total gate charge | | Qg | | | 28 | | |
| Gate-source charge | | Q _{gs} | $V_{DD} \approx 400 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 11 \text{ A}$ |) — | 18 | | nC |
| Gate-drain charge | | Q _{gd} | | | 10 | _ | |

Source-Drain Ratings and Characteristics (Ta = 25° C)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|-----------------|--|-----|------|------|------|
| Continuous drain reverse current (Note 1) | | | _ | _ | 11 | А |
| Pulse drain reverse current (Note 1) | IDRP | - (9) - | _ | _ | 44 | А |
| Forward voltage (diode) | VDSF | I _{DR} = 11 A, V _{GS} = 0 V | _ | _ | -1.7 | V |
| Reverse recovery time | trr | I _{DR} = 11 A, V _{GS} = 0 V, | _ | 1300 | _ | ns |
| Reverse recovery charge | Q _{rr} | dl _{DR} /dt = 100 A/μs | _ | 13 | _ | μC |

Marking

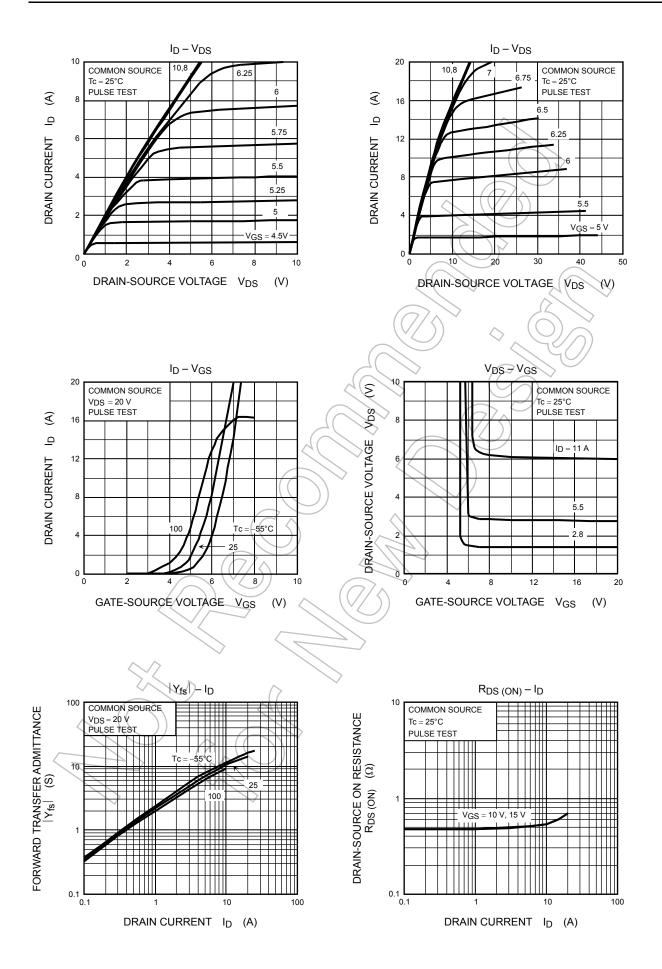


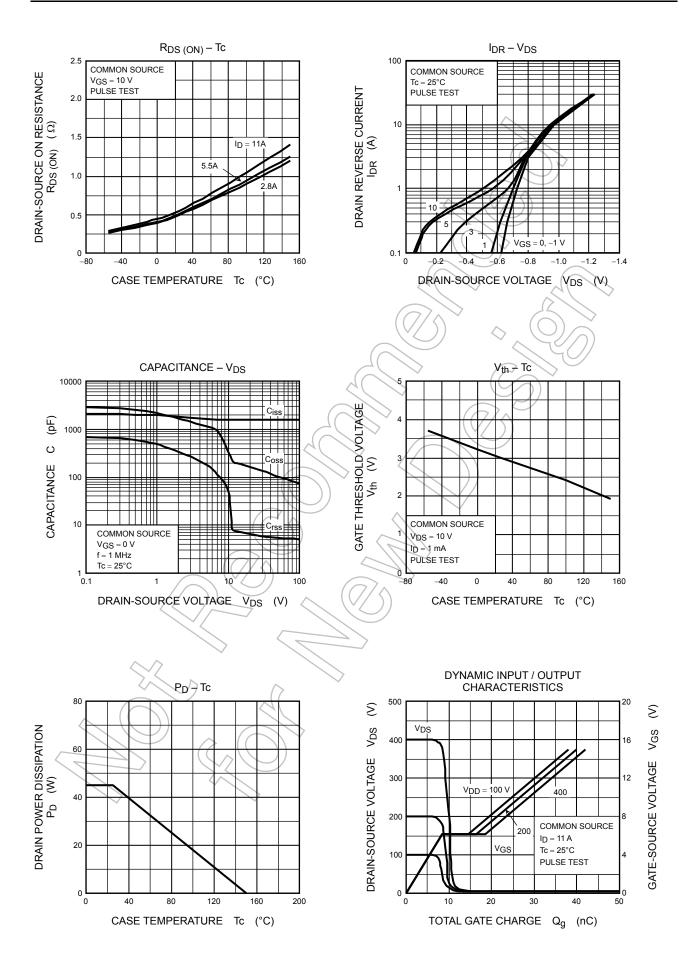
Note 4: A line under a Lot No. identifies the indication of product Labels.

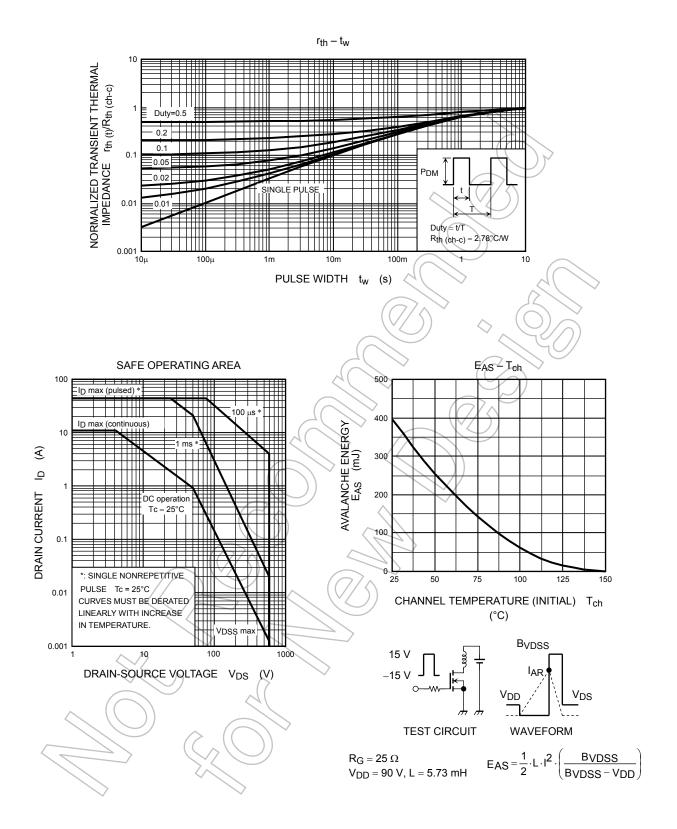
Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

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TOSHIBA







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